

# 0510-50A

50 Watts, 28 Volts, Class AB Defcom 500 - 1000 MHz

## **GENERAL DESCRIPTION**

The 0510-50A is a double input matched COMMON EMITTER broadband transistor specifically intended for use in the 500-1000 MHz frequency band. It may be operated in Class AB or C. Gold metallization and silicon diffused resistors ensure improved ruggedness and high reliability.

### ABSOLUTE MAXIMUM RATINGS

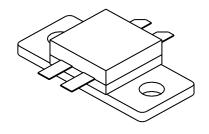
Maximum Power Dissipation @ 25°C 125 Watts

**Maximum Voltage and Current** 

BVcesCollector to Emiter Voltage60 VoltsBVeboEmitter to Base Voltage4.0 VoltsIcCollector Current3.7 A

**Maximum Temperatures** 

Storage Temperature  $-65 \text{ to } +200 ^{\circ}\text{C}$ Operating Junction Temperature  $+200 ^{\circ}\text{C}$  CASE OUTLINE 55AV - Style 2



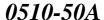
# **ELECTRICAL CHARACTERISTICS** @ 25 °C

SYMBOL	CHARACTERISTICS	TEST CONDITIONS	MIN	TYP	MAX	UNITS
Pout Pin Pg ηc VSWR	Power Output Power Input Power Gain Efficiency Load Mismatch Tolerance	F = 1000 MHz Vcc = 28 Volts Vcb = 28V, Po = 50W	50	7.0 50	12.5 5:1	Watts Watts dB %

BVebo	Emitter to Base Breakdown	Ie = 5  mA	4.0			Volts
BVces	Collector to Emitter Breakdown	Ic = 100  mA	60			Volts
BVceo	Collector to Emitter Breakdown	Ie = 50  mA	27			Volts
Cob	Output Capacitance	Vcb = 28 V, F = 1 MHz		27		pF
$\mathbf{h}_{ ext{FE}}$	DC - Current Gain	Vce = 5 V, Ic = 500 mA	10			_
θјс	Thermal Resistance				1.4	°C/W

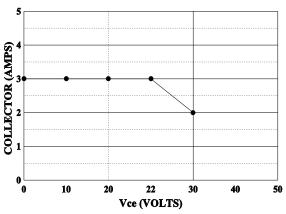
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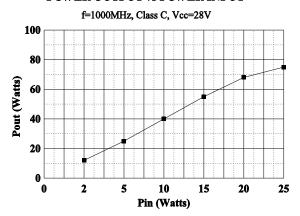




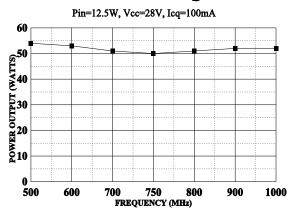
DC SAFE OPERATING AREA



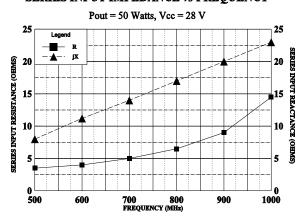
#### **POWER OUTPUT vs POWER INPUT**



#### POWER OUTPUT VS FREQUENCY



#### SERIES INPUT IMPEDANCE vs FREQUENCY



#### SERIES LOAD IMPENDANCE vs FREQUENCY

